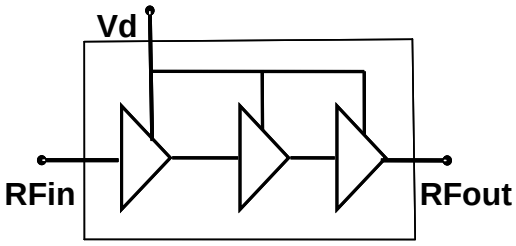
18 – 40 GHz Low Noise Amplifier Module

Features

- **Frequency Range: 18 - 40 GHz**
- **5 dB Noise Figure**
- **27 dB Gain**
- **13 dBm P1dB**
- **Single supply operation +12 V**
- **Input Return Loss of 15 dB (Typ)**
- **Output Return Loss of 10 dB (Typ)**
- **Nominal Bias 12V@ 175 mA**
- **0.15-um InGaAs pHEMT Technology**
- **Small form factor**

Functional Diagram



Typical Applications

- **Millimeter-wave Point-to-Point Radio**
- **LMDS**
- **SATCOM**
- **VSAT Applications**

Description

The ASL10008M2 is a connectorised LNA module operating in 18 – 40 GHz frequency range. The LNA exhibits 27 dB of nominal gain and has a max. noise figure of 5 dB. The typical input/output return loss of the LNA is about 15 and 10 dB respectively. The nominal 1dB compression point is 13dBm. The module operates from a single +12 V supply.

The LNA features a small form factor with field replaceable K-type connectors. The module can be used as drop-in if required.

Absolute Maximum Ratings (1)

Parameter	Absolute Maximum	Units
Drain bias voltage (Vd)	+15	volts
RF input power (RFin at Vd=12V)	+20	dBm
Operating temperature	-55 to +85	^{o}C
Storage Temperature	-65 to +150	^{o}C

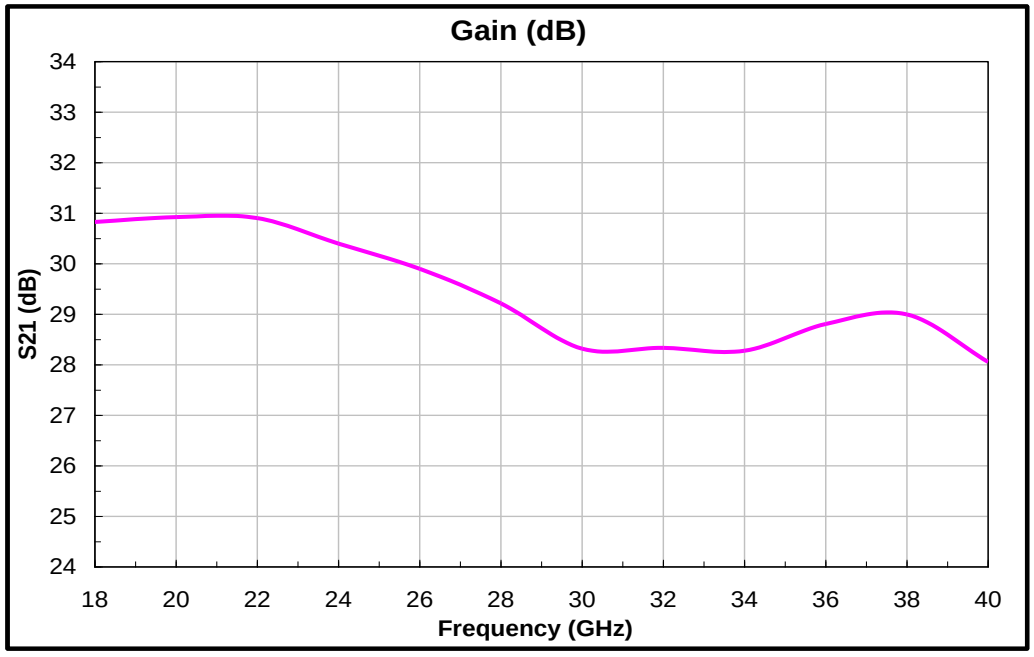
1. Operation beyond these limits may cause permanent damage to the component

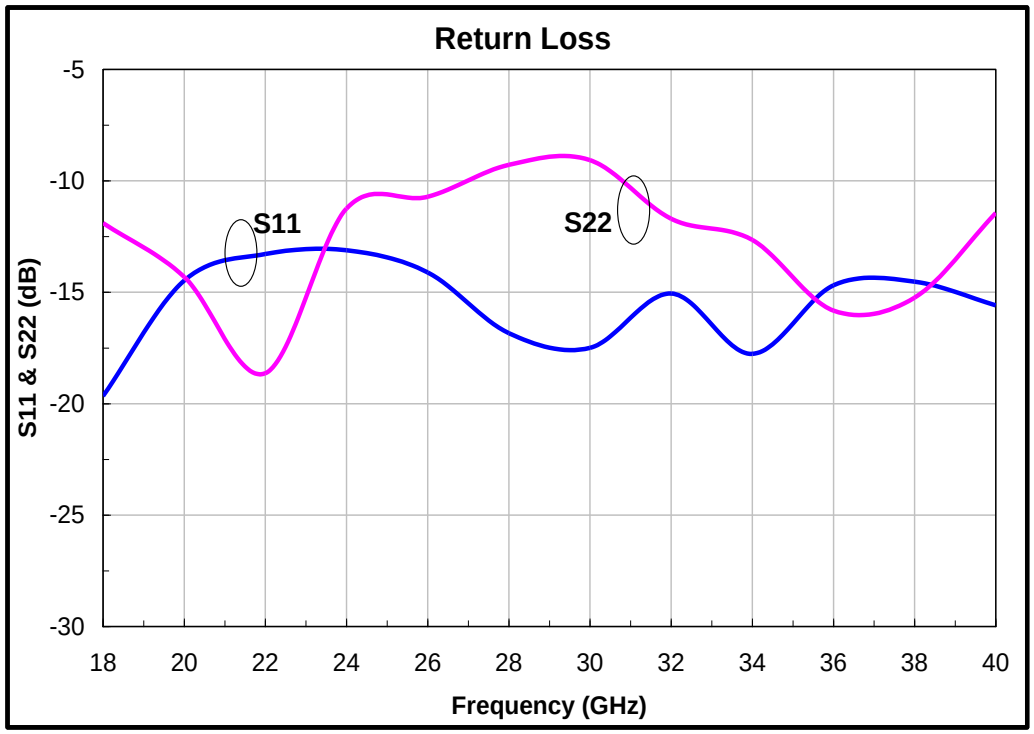
Electrical Specifications @ T_A = 25 °C, Vd = +12V, Zo =50 Ω

Parameter	Typ.	Units
Frequency Range	18 - 40	GHz
Gain	27	dB
Gain Flatness	±2	dB
Noise Figure (max.)	5	dB
Input Return Loss	15	dB
Output Return Loss	10	dB
Output Power (P1dB)	+13	dBm
Supply Current (Id)	175	mA

Test fixture data

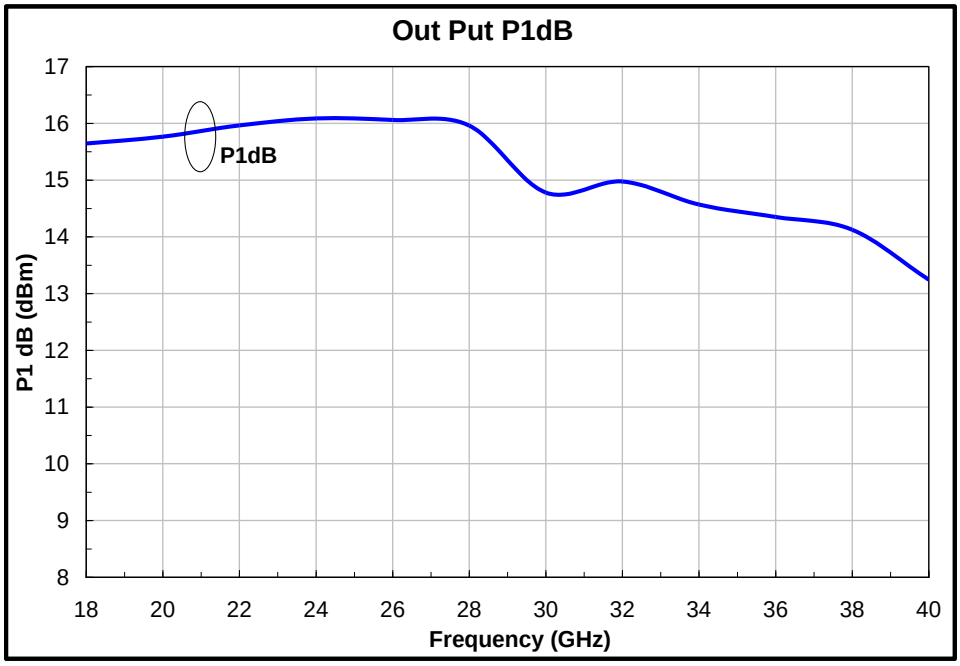
Vd =12 V, Total Current =175 mA , T_A = 25 °C





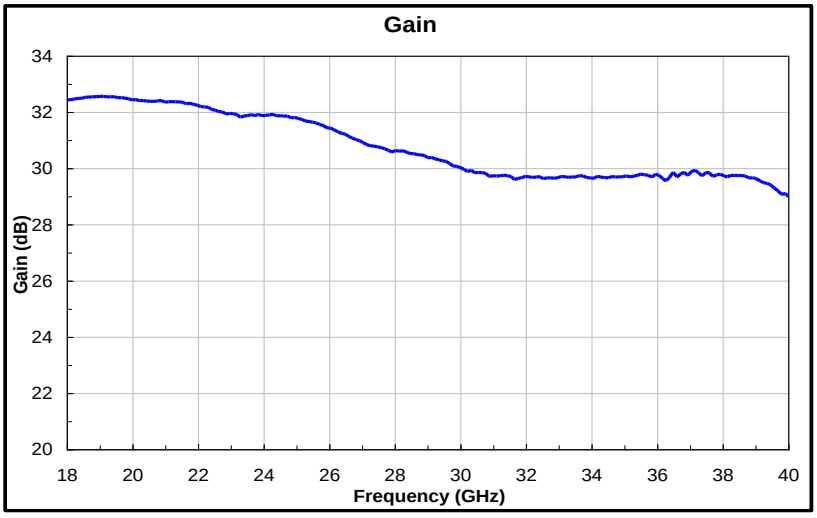
Test fixture data

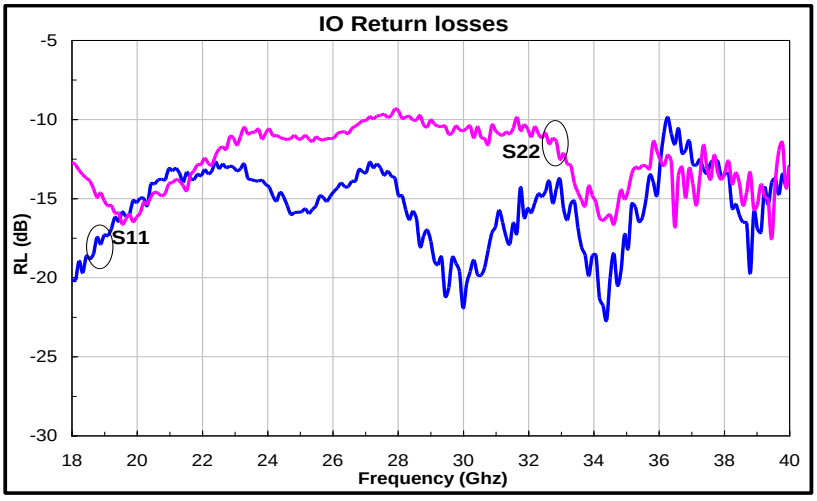
VD =12 V, Total Current =175 mA, T_A = 25 °C

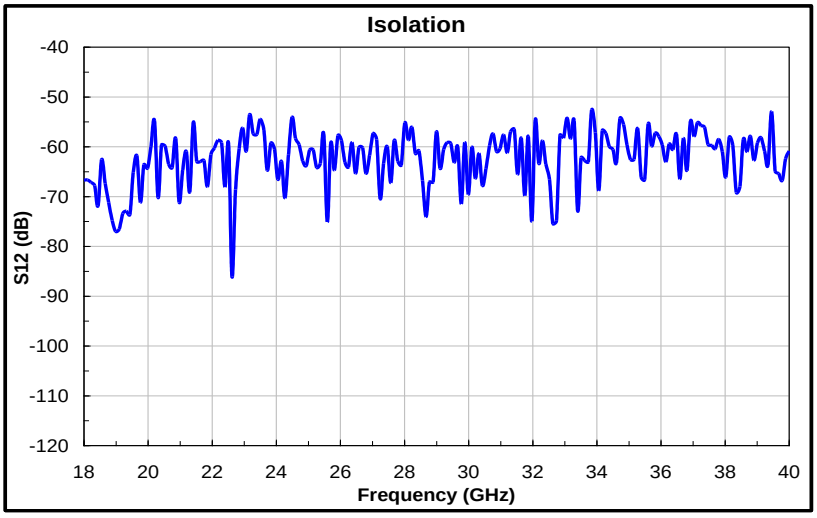


Test fixture data over Temperature

VD =12 V, Total Current =175 mA, Temperature= -10 °C

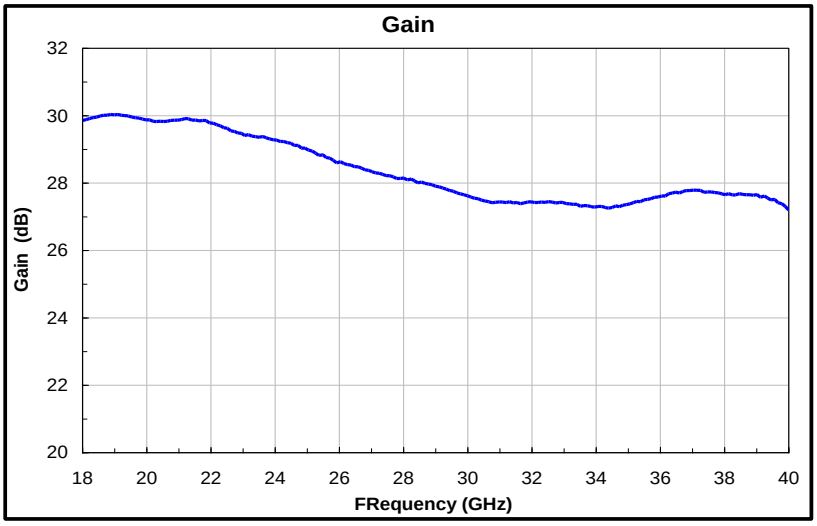


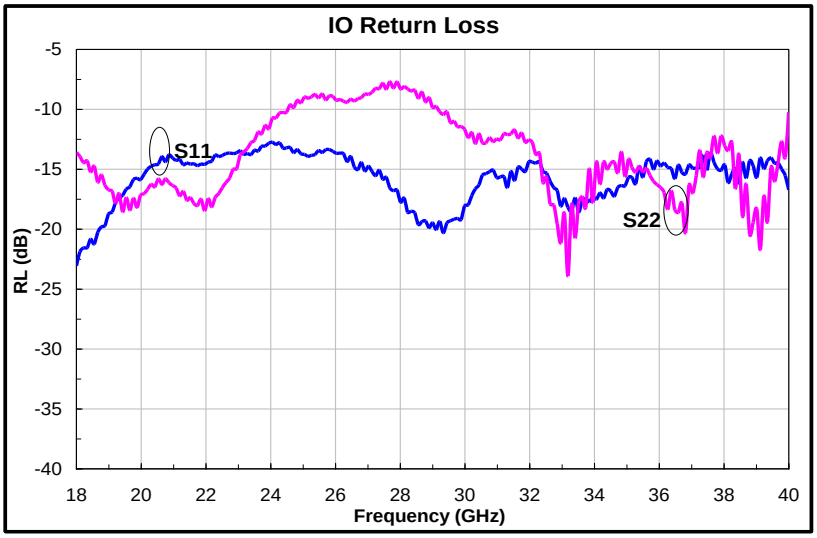


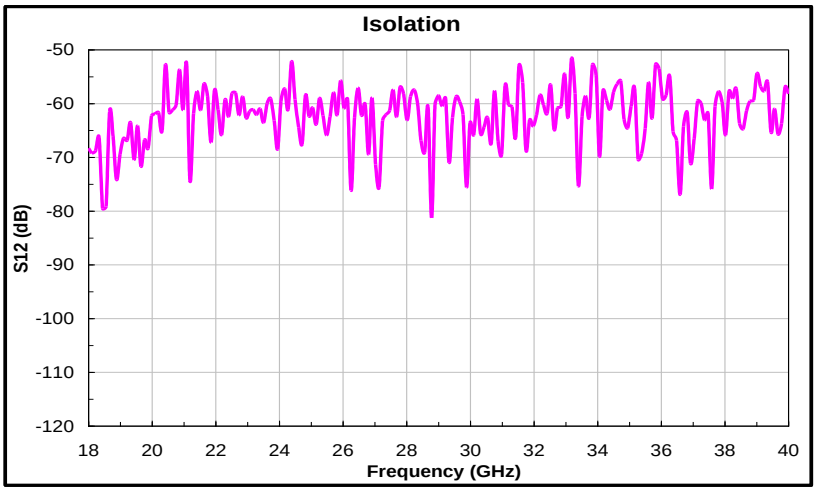


Test fixture data over Temperature

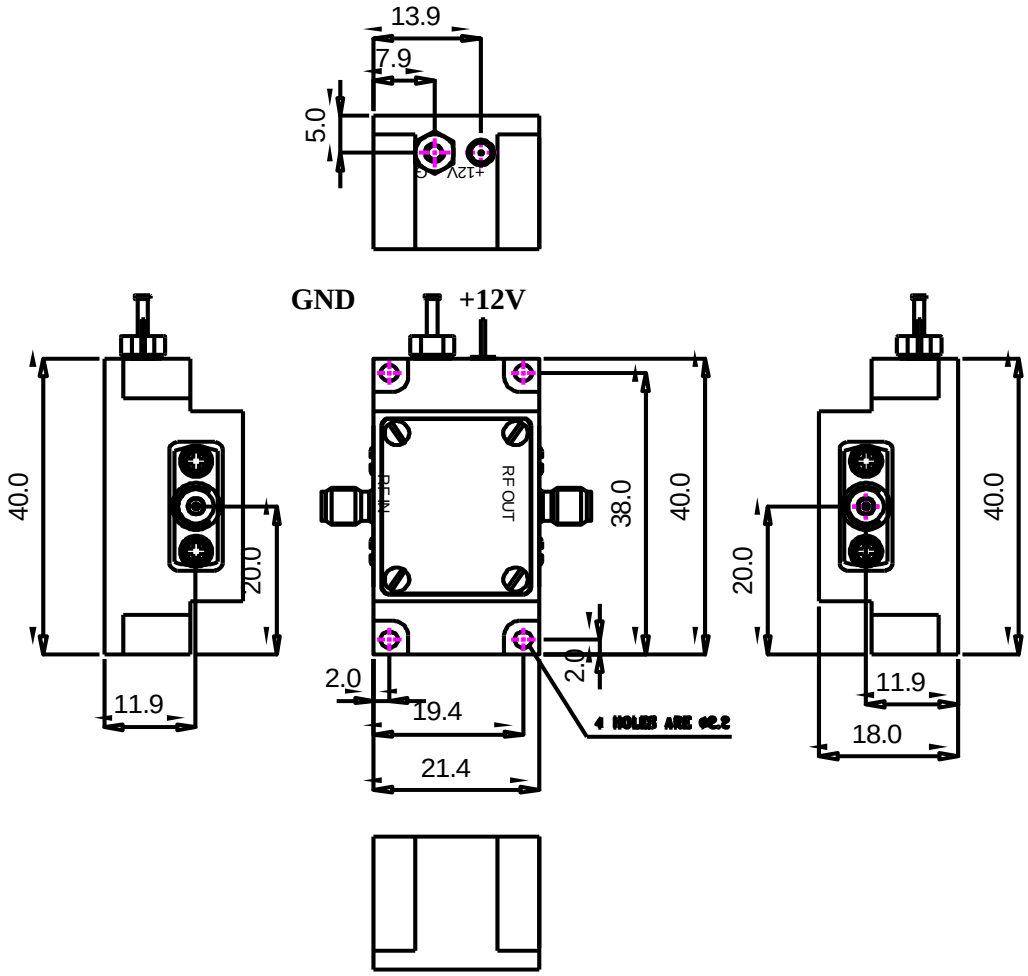
VD =12 V, Total Current =175 mA, Temperature = +55 °C







Mechanical Characteristics



Units: Millimeters

GaAs MMIC devices are susceptible to Electrostatic discharge. Proper precautions should be observed during handling, assembly & testing

All information and Specifications are subject to change without prior notice